NSN 5961-01-375-0804



Transistor - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5961-01-375-0804 **Inclosure Material:** Plastic **Overall Length:** 2.9 millimeters **Overall Height:** 1.3 millimeters **Overall Width:** 1.5 millimeters **End Application:** 6625-01-286-3566 **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: Sot-23 **Mounting Method: Terminal Features Provided:** Burn in **Cubic Measure:** 5.65 cubic meters **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 20.0 collector to base voltage/static/emitter open and 12.0 collector to emitter voltage/static/base open and 3.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 100.00 milliamperes source cutoff current and 1.00 microamperes base current, dc preset and 1.00 microamperes base current, dc major **Power Rating Per Characteristic:** 200.0 milliwatts any acceptable preset **Transfer Ratio:** 50.0 static forward current transfer ratio, common-emitter and 300.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a

No

Unit Of Measure:

Demilitarization:

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